Sheet <u>1</u> of <u>1</u>

Substitute Form PTO-(Modified)

Department of Commerce atent and Trademark Office

Attorney's Docket No. 07977-280001

Application No. 09/894,950

Information Disclosure Statement by Applicant (Use several sheets if necessary)

JUL 1 9 2005

Applicant

Shunpei Yamazaki et al

Filing Date June 27, 2001

Group Art Unit 2825

(37 CFR §1.98(b))

U.S. Patent Documents Filing Date Examiner Document Publication Desig. **Subclass** If Appropriate Patentee Class Number Date Initial ID 349 CYME 07/11/1997 10/12/1999 Zhang et al. 110 AA 5,966,193 AB AC AD ΑE AF AG ΑH ΑI ΑJ

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Examiner	Desig.	Document	Publication	Country or			Trans	lation
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	<u>No</u>
CYME	AL	11-087726	03/30/1999	JAPAN	_		AB	
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	AN				<u> </u>			
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	Other Do	cuments (inc	lude Author,	Title, Date, and	Place of P	ublication	<u>) </u>
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	AQ						
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Examiner Signature C. Juerkoul	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if no	it in conformance and not considered. Include copy of this form with

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Substitute Form PTO-1449

U.S. Department of Commerce Patent and Trademark Office

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Applicant

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Filing Date
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Group Art Unit 2825 289/

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Examiner Signature C. Swerkast	Date Considered

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